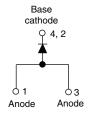


Vishay Semiconductors

Schottky Rectifier, 3.5 A





D-PAK	(IO-252AA)	

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	3.5 A			
V_{R}	40 V			
V _F at I _F	See Electrical table			
I _{RM}	24 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	8 mJ			

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-30WQ04FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	3.5	А				
V _{RRM}		40	V				
I _{FSM}	t _p = 5 μs sine	500	A				
V _F	3 Apk, T _J = 125 °C	0.49	V				
T _J		- 40 to 150	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-30WQ04FNPbF UNITS						
Maximum DC reverse voltage	V_{R}	40				
Maximum working peak reverse voltage	V_{RWM}	/ _{RWM} 40 V				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C, rectangular waveform					
Maximum peak one cycle non-repetitive surge current	l=a	I _{FSM} 5 μs sine or 3 μs rect. pulse 10 ms sine or 6 ms rect. pulse	Following any rated load condition and with rated	500	Α		
See fig. 7	IFSM		V _{RRM} applied	80			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	1.0	Α			

VS-30WQ04FNPbF

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		3 A T _J = 25 °C	0.53			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	11 = 23 0	0.67	V	
See fig. 1	VFM (*)	3 A	- T _{.I} = 125 °C	0.49		
		6 A	- IJ = 125 C	0.62		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	2	mA	
See fig. 2	'RM \"	T _J = 125 °C	V _R = nateu V _R	24		
Threshold voltage	V _{F(TO)}	T - T maximum		0.34	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		37.33	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	189	pF		
Typical series inductance	L _S	Measured lead to lead 5 n	5.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W		
Approximate weight			0.3	g		
Approximate weight			0.01	OZ.		
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	04FN		

Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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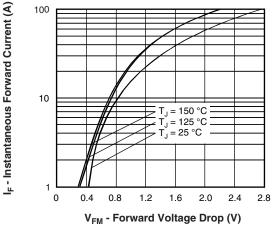


Fig. 1 - Maximum Forward Voltage Drop Characteristics

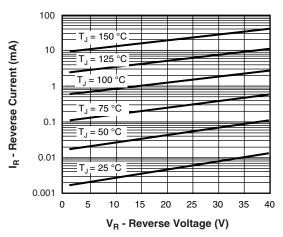


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

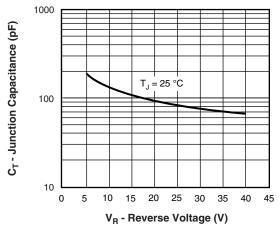


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

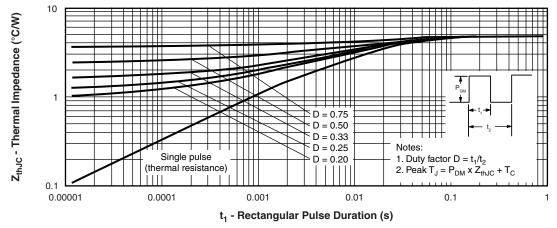


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Schottky Rectifier, 3.5 A



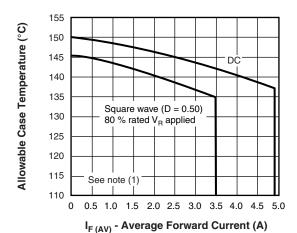


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

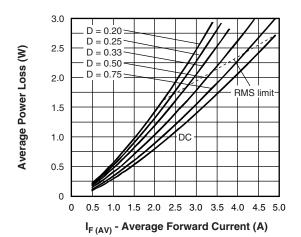


Fig. 6 - Forward Power Loss Characteristics

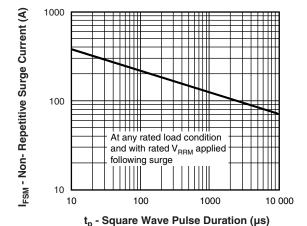


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{th,JC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = 80 \text{ \% rated V}_{\text{R}} \\ \end{array}$

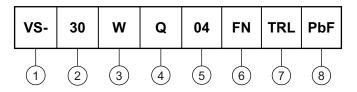


Schottky Rectifier, 3.5 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (3.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (04 = 40 V)

6 - FN = TO-252AA (D-PAK)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

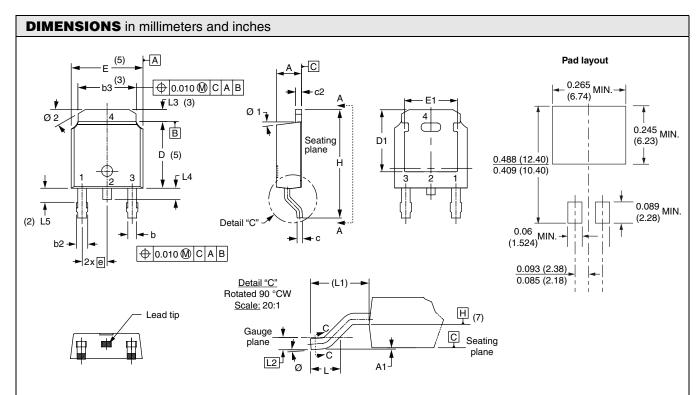
PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			
SPICE model	www.vishay.com/doc?95288			



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	ETERS	INCHES		NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	2.74 BSC		0.108 REF.	
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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